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UHF power LDMOS transistor Rev. 4 — 18 February 2016

Product profile 1.

1.1 General description

A 600 W LDMOS RF power transistor for broadcast Doherty transmitter applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. **Application information**

RF performance at V_{DS} = 50 V in an ultra wide Doherty application.

Test signal	f	P _{L(AV)}	G _p	η _D	IMD _{shldr}	PAR
	(MHz)	(W)	(dB)	(%)	(dBc)	(dB)
DVB-T (8k OFDM)	470 to 860	115 to 134 [1]	17	40 to 48 1	-38 to -44 [2]	8 [3]

- [1] Depending on selected channel.
- [2] Depending on exciter used.
- [3] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- High efficiency
- High power gain
- Excellent ruggedness (VSWR ≥ 40 : 1 through all phases)
- Excellent thermal stability
- Integrated ESD protection
- One Doherty design covers the full bandwidth from 470 MHz to 860 MHz
- Internal input matching for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Broadcast transmitter applications in the UHF band
- Digital broadcasting

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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
BLF888D) (SOT539A)		
1	drain1 (peak)		
2	drain2 (main)		
3	gate1 (peak)		
4	gate2 (main)	3 4	3 5
5	source	[1]	
			 sym117
BLF888D	OS (SOT539B)		
1	drain1 (peak)		
2	drain2 (main)		
3	gate1 (peak)	5	
4	gate2 (main)	3 4	3 - 5
5	source	[1]	
			[™]
			2 sym117

[1] Connected to flange.

3. Ordering information

Table 3.Ordering information

Type number	Packag	Package			
	Name	Description	Version		
BLF888D	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLF888DS	-	earless flanged balanced ceramic package; 4 leads	SOT539B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage			-	104	V
V _{GS}	gate-source voltage			-0.5	+11	V
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature		[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5.	Thermal	characteristics
	1 II O I II G	onaraotoriotioo

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case		0.27	K/W
		T _{case} = 90 °C; V _{DS} = 50 V; P _L = 115 W; PAR = 8 dB	0.16	K/W

[1] Measured under DC test conditions, with peak section off.

[2] Measured in an ultra wide Doherty application, using a DVB-T (8k OFDM) signal, PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 2.4 mA	104	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 240 mA	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	0.061	2.8	μA
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	-	37	-	A
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	V _{GS} = V _{GS(th)} + 3.75 V; I _D = 8.5 A	-	120	-	mΩ

Table 7.AC characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	210	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	70	-	pF
C _{rss}	reverse transfer capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	1.3	-	pF

Table 8.RF characteristics

 V_{DS} = 50 V; I_{Dq} = 1.3 A; T_{case} = 25 °C unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test sigr	nal: 2-tone CW					
P _{L(AV)}	average output power	f ₁ = 860 MHz; f ₂ = 860.1 MHz	-	250	-	W
G _p	power gain	f ₁ = 860 MHz; f ₂ = 860.1 MHz	19	21	-	dB
η _D	drain efficiency	f ₁ = 860 MHz; f ₂ = 860.1 MHz	43	45	-	%
IMD3	third-order intermodulation distortion	f ₁ = 860 MHz; f ₂ = 860.1 MHz	-	-32	-29	dBc
Test signal: pulsed CW						
P _{L(3dB)}	output power at 3 dB gain compression	f = 860 MHz; t _p = 100 μs; δ = 10 %	540	580	-	W

7. Test information

7.1 Ruggedness in Doherty operation

The BLF888D and BLF888DS are capable of withstanding a load mismatch corresponding to VSWR \ge 40 : 1 through all phases under the following conditions: V_{DS} = 50 V; f = 810 MHz at rated load power.

7.2 Test circuit

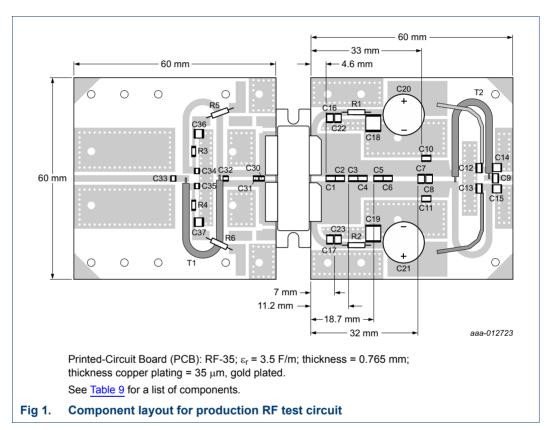


Table 9.List of componentsFor test circuit see Figure 1.

For test circuit see <u>Figure 1</u> .					
Component	Description	Value	Remarks		
C1	multilayer ceramic chip capacitor	12 pF [1]			
C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	8.2 pF [1]			
C7	multilayer ceramic chip capacitor	6.8 pF [2]			
C8	multilayer ceramic chip capacitor	4.7 pF [2]			
C9, C12, C13	multilayer ceramic chip capacitor	100 pF [1]			
C10, C11	multilayer ceramic chip capacitor	10 pF [1]			
C14, C15	multilayer ceramic chip capacitor	4.7 μF, 50 V			
C16, C17	multilayer ceramic chip capacitor	3.6 pF [2]			
C18, C19	multilayer ceramic chip capacitor	4.7 μF, 50 V			
C20, C21	electrolytic capacitor	470 μF, 63 V			

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Table 9.	List of componentscontinued	1
For test cir	cuit see Figure 1.	

Component	Description	Value	Remarks
C22, C23	multilayer ceramic chip capacitor	47 pF [2]	
C30	multilayer ceramic chip capacitor	15 pF [3]	
C31	multilayer ceramic chip capacitor	5.6 pF [3]	
C32	multilayer ceramic chip capacitor	2.7 pF [3]	
C33, C34, C35	multilayer ceramic chip capacitor	100 pF [3]	
C36, C37	multilayer ceramic chip capacitor	470 μF, 50 V	
R1, R2	resistor	10 Ω	
R3, R4	resistor	5.6 Ω	SMD 1206
R5, R6	resistor	100 Ω	
R3, R4	resistor	510 Ω	SMD 1206
T1, T2	semi rigid coax	25 Ω, length = 160 mm	Micro-Coax UT-090C-25

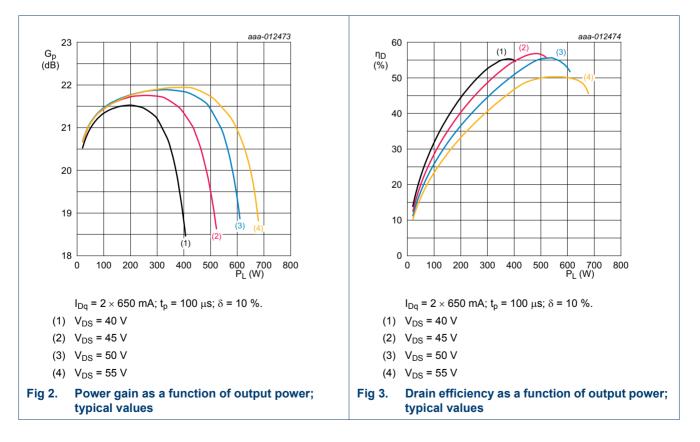
[1] American Technical Ceramics type 180R or capacitor of same quality.

[2] American Technical Ceramics type 100B or capacitor of same quality.

[3] American Technical Ceramics type 100A or capacitor of same quality.

7.3 Graphical data

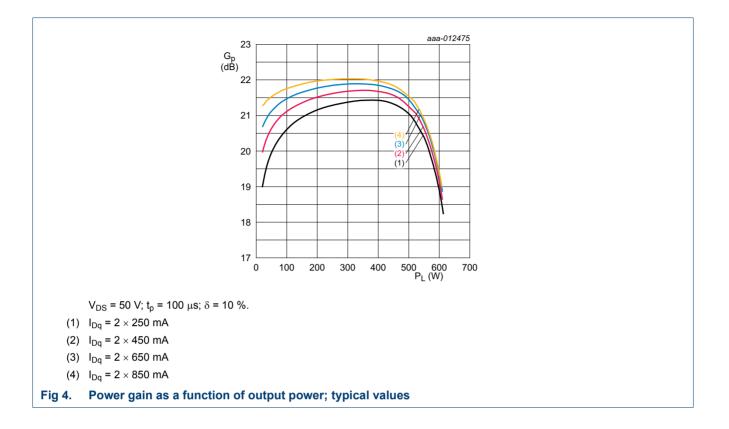
7.3.1 1-Tone CW pulsed



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BLF888D; BLF888DS

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8. Package outline

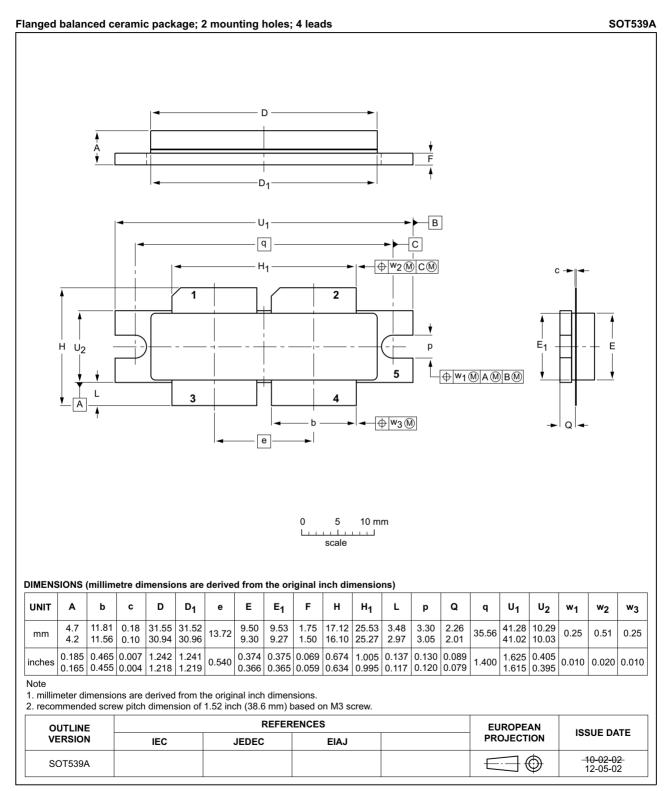


Fig 5. Package outline SOT539A

BLF888D_BLF888DS

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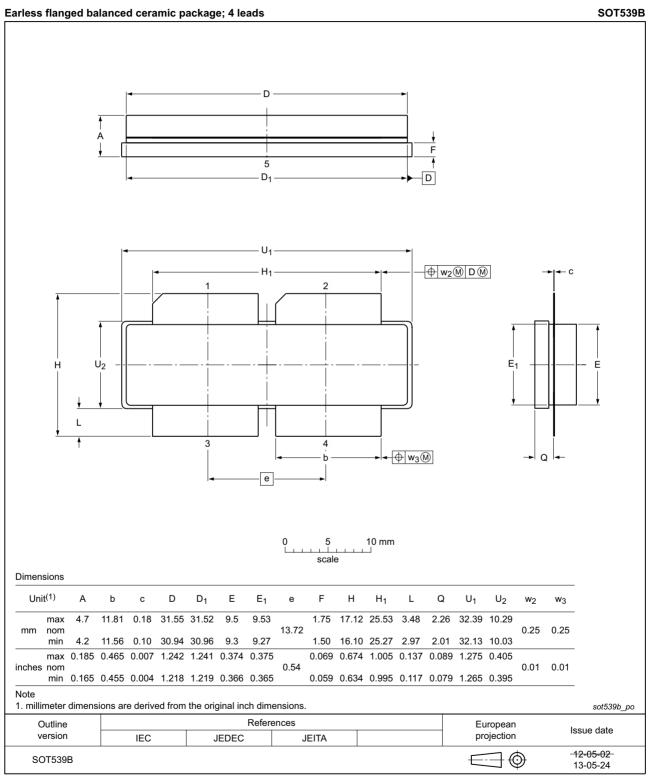


Fig 6. Package outline SOT539B

BLF888D_BLF888DS

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations					
Acronym	Description				
CCDF	Complementary Cumulative Distribution Function				
CW	Continuous Wave				
DVB-T	Digital Video Broadcast - Terrestrial				
ESD	ElectroStatic Discharge				
LDMOS	Laterally Diffused Metal-Oxide Semiconductor				
MTF	Median Time to Failure				
OFDM	Orthogonal Frequency Division Multiplexing				
PAR	Peak-to-Average Ratio				
SMD	Surface Mounted Device				
UHF	Ultra High Frequency				
VSWR	Voltage Standing-Wave Ratio				

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF888D_BLF888DS v.4	20160218	Product data sheet	-	BLF888D_BLF888DS#3
Modifications:	• <u>Table 8 on page 3</u> : unit of last row has been corrected from "dB" to "W"			
BLF888D_BLF888DS#3	20150901	Product data sheet	-	BLF888D_BLF888DS v.2
BLF888D_BLF888DS v.2	20140627	Product data sheet	-	BLF888D_BLF888DS v.1
BLF888D_BLF888DS v.1	20140305	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Date of release: 18 February 2016 Document identifier: BLF888D_BLF888DS

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